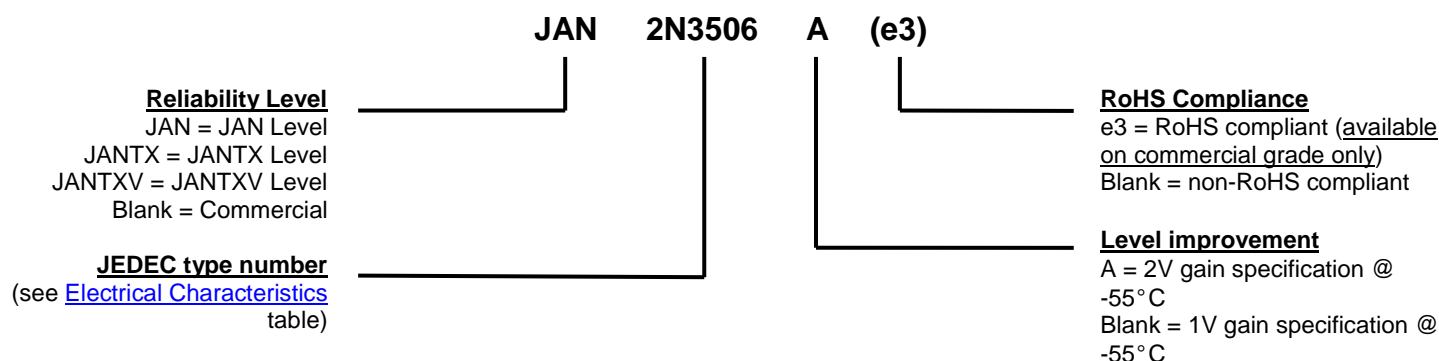


MECHANICAL and PACKAGING

- CASE: Hermetically sealed, kovar base, nickel cap.
- TERMINALS: Leads are kovar, nickel plated, and finish is solder dip (Sn63/Pb37). Can be RoHS compliant (commercial grade only) with pure matte-tin (commercial grade only).
- MARKING: Part number, date code, manufacturer's ID.
- POLARITY: NPN (see package outline).
- WEIGHT: Approximately 1.064 grams.
- See [Package Dimensions](#) on last page.

PART NOMENCLATURE

SYMBOLS & DEFINITIONS

Symbol	Definition
C_{obo}	Common-base open-circuit output capacitance.
I_{CEO}	Collector cutoff current, base open.
I_{CEX}	Collector cutoff current, circuit between base and emitter.
I_{EBO}	Emitter cutoff current, collector open.
h_{FE}	Common-emitter static forward current transfer ratio.
V_{CEO}	Collector-emitter voltage, base open.
V_{CBO}	Collector-emitter voltage, emitter open.
V_{EBO}	Emitter-base voltage, collector open.

ELECTRICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise noted)

OFF CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Collector-Emitter Breakdown Voltage $I_C = 10\text{ mA}$	$V_{(BR)CEO}$	40 50		V
Collector-Emitter Cutoff Current $V_{CE} = 40\text{ V}; V_{EB} = 4\text{ V}$ $V_{CE} = 60\text{ V}; V_{EB} = 4\text{ V}$	I_{CEX}		1.0 1.0	μA
Collector-Base Breakdown Voltage $I_C = 100\text{ }\mu\text{A}$	$V_{(BR)CBO}$	60 80		V
Emitter-Base Breakdown Voltage $I_E = 10\text{ }\mu\text{A}$	$V_{(BR)EBO}$	5		V

ON CHARACTERISTICS ⁽¹⁾

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Forward-Current Transfer Ratio $I_C = 500\text{ mA}, V_{CE} = 1\text{ V}$	h_{FE}	50 35	250 175	
Forward-Current Transfer Ratio $I_C = 1.5\text{ A}, V_{CE} = 2\text{ V}$	h_{FE}	40 30	200 150	
Forward-Current Transfer Ratio $I_C = 2.5\text{ A}, V_{CE} = 3\text{ V}$	h_{FE}	30 25		
Forward-Current Transfer Ratio $I_C = 3.0\text{ A}, V_{CE} = 5\text{ V}$	h_{FE}	25 20		
Forward-Current Transfer Ratio $I_C = 500\text{ mA}, V_{CE} = 1.0\text{ V @ } -55^\circ\text{C}$	h_{FE}	25 17		
Forward-Current Transfer Ratio $I_C = 500\text{ mA}, V_{CE} = 2.0\text{ V @ } -55^\circ\text{C}$	h_{FE}	25 17		
Collector-Emitter Saturation Voltage $I_C = 500\text{ mA}, I_B = 50\text{ mA}$	$V_{CE(sat)}$		0.5	V
Collector-Emitter Saturation Voltage $I_C = 1.5\text{ A}, I_B = 150\text{ mA}$	$V_{CE(sat)}$		1.0	V
Collector-Emitter Saturation Voltage $I_C = 2.5\text{ A}, I_B = 250\text{ mA}$	$V_{CE(sat)}$		1.5	V
Base-Emitter Saturation Voltage $I_C = 500\text{ mA}, I_B = 50\text{ mA}$	$V_{BE(sat)}$		1.0	V
Base-Emitter Saturation Voltage $I_C = 1.5\text{ A}, I_B = 150\text{ mA}$	$V_{BE(sat)}$	0.8	1.3	V
Base-Emitter Saturation Voltage $I_C = 2.5\text{ A}, I_B = 250\text{ mA}$	$V_{BE(sat)}$		2.0	V

(1) Pulse Test: Pulse Width = 300 μs , duty cycle $\leq 2.0\%$.

ELECTRICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise noted)

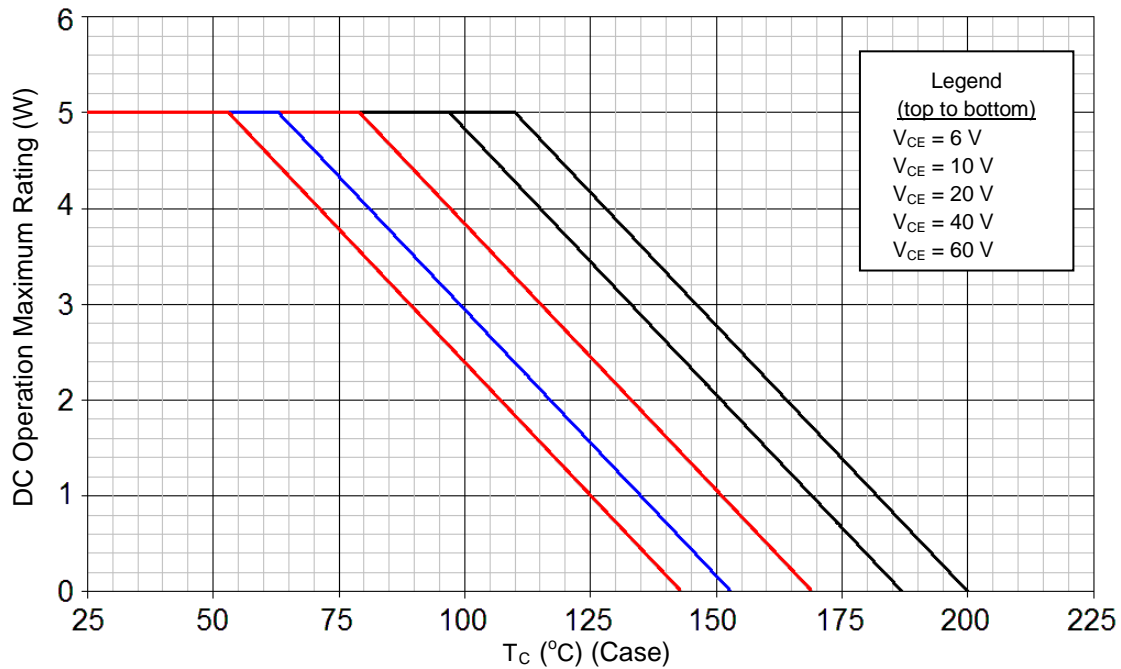
DYNAMIC CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio $I_C = 100\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 20\text{ MHz}$	$ h_{fe} $	3.0	15	
Output Capacitance $V_{CB} = 10\text{ V}$, $I_E = 0$, $100\text{ kHz} \leq f \leq 1.0\text{ MHz}$	C_{obo}		40	pF
Input Capacitance $V_{EB} = 3.0\text{ V}$, $I_C = 0$, $100\text{ kHz} \leq f \leq 1.0\text{ MHz}$	C_{ibo}		300	pF

SWITCHING CHARACTERISTICS ⁽²⁾

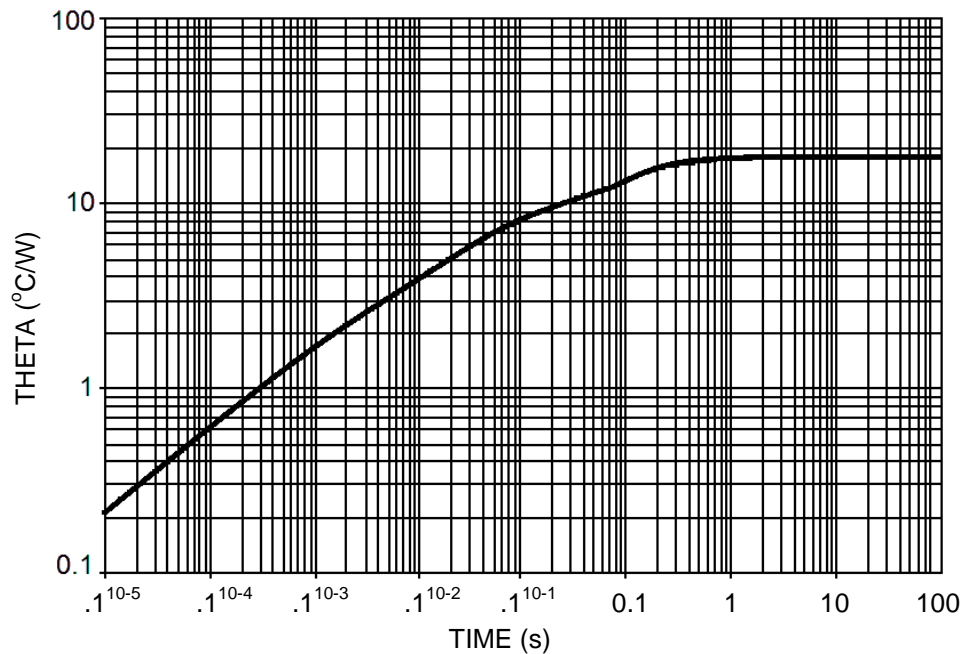
Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Delay Time $I_C = 1.5\text{ A}$, $I_{B1} = 150\text{ mA}$	t_d		15	ns
Rise Time $I_C = 1.5\text{ A}$, $I_{B1} = 150\text{ mA}$	t_r		30	ns
Storage Time $I_C = 1.5\text{ A}$, $I_{B1} = I_{B2} = 150\text{ mA}$	t_s		55	ns
Fall Time $I_C = 1.5\text{ A}$, $I_{B1} = I_{B2} = 150\text{ mA}$	t_f		35	ns

(2) Consult MIL-PRF-19500/349 for additional information.

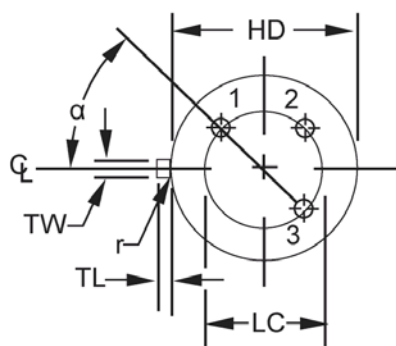
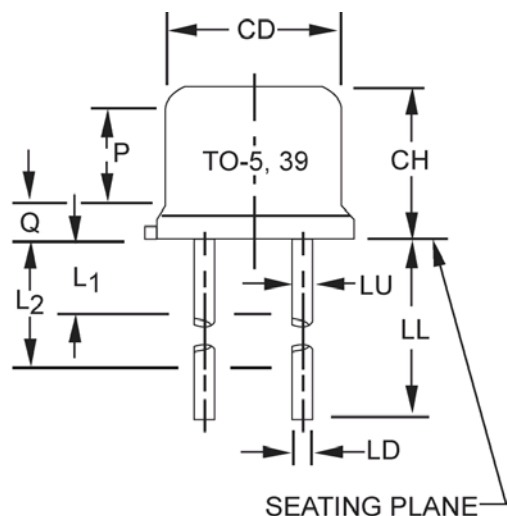
GRAPHS

FIGURE 1

Temperature-Power Derating Curve

NOTE: Thermal Resistance Junction to Case = $18.0\text{ }^{\circ}\text{C/W}$


FIGURE 2

Maximum Thermal Impedance ($R_{\theta JC}$)

PACKAGE DIMENSIONS


Symbol	Dimensions				Note
	Inches		Millimeters		
	Min	Max	Min	Max	
CD	0.305	0.335	7.75	8.51	
CH	0.240	0.260	6.10	6.60	
HD	0.335	0.370	8.51	9.40	
LC	0.200 TP		5.08 TP		6
LD	0.016	0.021	0.41	0.53	7, 8
LL	See notes 7, 8, 11				
LU	0.016	0.019	0.41	0.48	7, 8
L1		0.050		1.27	7, 8
L2	0.250		6.35		7, 8
P	0.100		2.54		5
Q		0.050		1.27	4
TL	0.029	0.045	0.74	1.14	3
TW	0.028	0.034	0.71	0.86	2
r		0.010		0.25	10
α	45° TP		45° TP		6

NOTES:

1. Dimension are in inches.
2. Millimeters are given for general information only.
3. Beyond r (radius) maximum, TH shall be held for a minimum length of .011 (0.28 mm).
4. Dimension TL measured from maximum HD.
5. Body contour optional within zone defined by HD, CD, and Q.
6. Leads at gauge plane .054 +.001 -.000 inch (1.37 +0.03 -0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
7. Dimension LU applies between L1 and L2. Dimension LD applies between L2 and LL minimum. Diameter is uncontrolled in L1 and beyond LL minimum.
8. All three leads.
9. The collector shall be internally connected to the case.
10. Dimension r (radius) applies to both inside corners of tab.
11. Dimension LL shall be .5 inches (12.7mm) minimum and .75 inches (19.0 mm) maximum.
12. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.
13. Lead 1 = emitter, lead 2 = base, lead 3 = collector.